

# TSM1011

# CONSTANT VOLTAGE AND CONSTANT CURRENT CONTROLLER FOR BATTERY CHARGERS AND ADAPTORS

#### ADVANCE DATA

- CONSTANT VOLTAGE AND CONSTANT CURRENT CONTROL
- LOW VOLTAGE OPERATION
- LOW EXTERNAL COMPONENT COUNT
- CURRENT SINK OUTPUT STAGE
- EASY COMPENSATION

#### **VOLTAGE REFERENCE**

- FIXED OUTPUT VOLTAGE REFERENCE 2.5V
- 0.5% AND 1% VOLTAGE PRECISION

#### DESCRIPTION

TSM1011 is a highly integrated solution for SMPS applications requiring CV (constant voltage) and CC (constant current) mode.

TSM1011 integrates one voltage reference and two operational amplifiers (with ORed outputs - common collectors).

The voltage reference combined with one operational amplifier makes it an ideal voltage controller. The other operational, combined with few external resistors and the voltage reference, can be used as a current limiter.

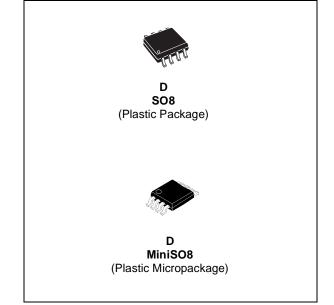
#### **APPLICATIONS**

- ADAPTERS
- BATTERY CHARGERS

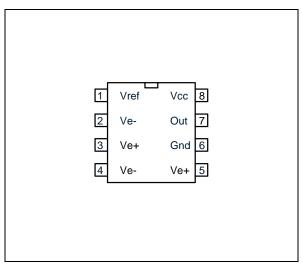
#### **ORDER CODE**

Part	Temperature	Pacl	kage	Morking	
Number	Range	S	D	Marking	
TSM1011I	0 to 105°C		•	M1011	
TSM1011AI	0 to 105°C		•	M1011A	
TSM1011I	0 to 105°C	٠		M802	
TSM1011AI	0 to 105°C	٠		M803	

 ${\rm D}$  = Small Outline Package (SO) - also available in Tape & Reel (DT  ${\rm S}$  = Small Outline Package (MiniSO8) - also available in Tape & Reel (ST)



#### **PIN CONNECTIONS** (top view)



# **PIN DESCRIPTION**

# SO8 & MiniSO8 Pinout

Name	Pin #	Туре	Function		
Vref	1	Analog Output	Voltage Reference		
Ve-	2	Analog Input	Input pin of the operationnal amplifier		
Ve+	3	Analog Input	Input pin of the operationnal amplifier		
Ve-	4	Analog Input	Input pin of the operationnal amplifier		
Ve+	5	Analog Input	Input pin of the operationnal amplifier		
Gnd	6	Power Supply	Ground Line. 0V Reference For All Voltages		
Out	7	Analog Output	Output of the two operational amplifier		
Vcc	8	Power Supply	Power supply line.		

# **ABSOLUTE MAXIMUM RATINGS**

Symbol	DC Supply Voltage	Value	Unit
Vcc	DC Supply Voltage (50mA =< Icc)	-0.3V to Vz	V
Vi	Input Voltage	-0.3 to Vcc	V
PT	Power dissipation		W
Toper	Operational temperature	0 to 105	°C
Tstg	Storage temperature	-55 to 150	°C
Tj	Junction temperature	150	°C
Iref	Voltage reference output current	10	mA
ESD	Electrostatic Discharge	2	KV
Rthja	Thermal Resistance Junction to Ambient Mini SO8 package		°C/W
Rthja	Thermal Resistance Junction to Ambient DIP8 package		°C/W

# **OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
Vcc	DC Supply Conditions	4.5 to Vz	V

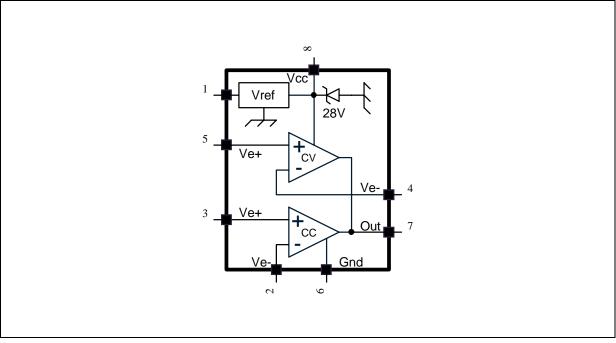
# **ELECTRICAL CHARACTERISTICS**

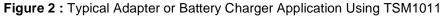
Tamb = 25°C and Vcc = +18V (unless otherwise specified)

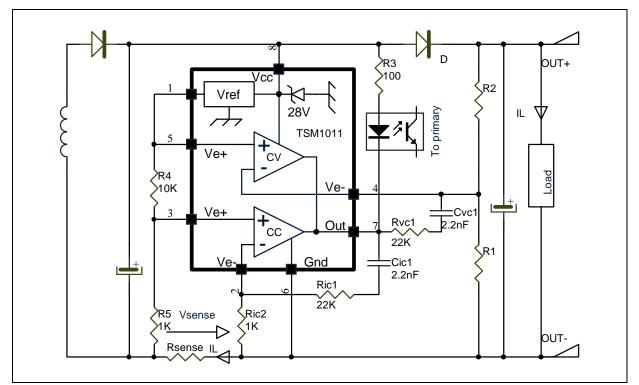
Symbol	Parameter	Test Condition	Min	Тур	Мах	Unit
Total Curi	ent Consumption		1	J		
lcc	Total Supply Current, excluding current in Voltage Reference.	Vcc = 18V, no load Tmin. < Tamb < Tmax.			1	mA
Vz	Vcc clamp voltage	Icc = 50mA		28		V
Operators	5					
V <sub>io</sub>	Input Offset Voltage TSM1011 TSM1011A	$T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $T_{amb} = 25^{\circ}C$		1 0.5	4 5 2 3	mV
		$T_{min.} \le T_{amb} \le T_{max.}$		7	Ū	V/00
DV <sub>io</sub>	Input Offset Voltage Drift Input Offset Current	$T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		2	30 50	μV/°C nA
l <sub>ib</sub>	Input Bias Current	$\begin{array}{l} T_{amb} = 25^{\circ}C\\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array}$		20 50	150 200	nA
SVR	Supply Voltage Rejection Ration	$V_{CC} = 4.5V$ to 28V	65	100		dB
Vicm	Input Common Mode Voltage Range		0		Vcc-1.5	V
CMR	Common Mode Rejection Ratio	$\begin{array}{l} T_{amb} = 25^\circC \\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array}$	70 60	85		dB
Output st	age	•			•	
Gm	Transconduction Gain. Sink Current Only <sup>1)</sup>	$\begin{array}{l} T_{amb} = 25^{\circ}C \\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array}$	1	3.5 2.5		mA/mV
Vol	Low level output voltage at 10 mA sinking current			200		mV
los	Output Short Circuit Current. Output to Vcc. Sink Current Only	$\begin{array}{l} T_{amb} = 25^{\circ}C \\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array}$		27	50	mA
Voltage re						
V <sub>ref</sub>	Reference Input Voltage, Iload=1mA TSM1011 1% precision	$\begin{array}{l} T_{amb} = 25^\circC \\ T_{min.} \leq T_{amb} \leq T_{max.} \\ T_{amb} = 25^\circC \end{array}$		2.5 TBD		V
	TSM1011A 0.5% precision	$T_{min.} \le T_{amb} \le T_{max.}$		2.5		
$\Delta V_{\text{ref}}$	Reference Input Voltage Deviation Over Temperature Range	$T_{min.} \leq T_{amb} \leq T_{max.}$		20	30	mV
RegLine	Reference input voltage deviation over Vcc range.	Iload = 5mA			20	mV
RegLoad	Reference input voltage deviation over output current.	Vcc = 18V, 0 < Iload < 10mA			10	mV

1. The current depends on the difference voltage beween the negative and the positive inputs of the amplifier. If the voltage on the minus input is 1mV higher than the positive amplifier, the sinking current at the output OUT will be increased by 3.5mA.

# Figure 1 : Internal Schematic







In the above application schematic, the TSM1011 is used on the secondary side of a flyback adapter (or battery charger) to provide an accurate control of voltage and current. The above feedback loop is made with an optocoupler.

# PRINCIPLE OF OPERATION AND APPLICATION HINTS

### 1. Voltage and Current Control

#### 1.1. Voltage Control

The voltage loop is controlled via a first transconductance operational amplifier, the resistor bridge R1, R2, and the optocoupler which is directly connected to the output.

The relation between the values of R1 and R2 should be chosen as writen in Equation 1.

R1 = R2 x Vref / (Vout - Vref) Eq1

Where Vout is the desired output voltage.

To avoid the discharge of the load, the resistor bridge R1, R2 should be highly resistive. For this type of application, a total value of  $100K\Omega$  (or more) would be appropriate for the resistors R1 and R2.

As an example, with R2 =  $100K\Omega$ , Vout = 4.10V, Vref = 2.5V, then R1 =  $41.9K\Omega$ .

Note that if the low drop diode should be inserted between the load and the voltage regulation resistor bridge to avoid current flowing from the load through the resistor bridge, this drop should be taken into account in the above calculations by replacing Vout by (Vout + Vdrop).

# 1.2. Current Control

The current loop is controlled via the second trans-conductance operational amplifier, the sense resistor Rsense, and the optocoupler.

Vsense threshold is achieved externally by a resistor bridge tied to the Vref voltage reference. Its middle point is tied to the positive input of the current control operational amplifier, and its foot is to be connected to lower potential point of the sense resistor as shown on the following figure. The resistors of this bridge are matched to provide the best precision possible

The control equation verifies:

Rsense x Ilim = Vsense eq2 Vsense = R5\*Vref/(R4+R5)

Ilim = R5\*Vref/(R4+R5)\*Rsense eq2'

where Ilim is the desired limited current, and Vsense is the threshold voltage for the current control loop.

Note that the Rsense resistor should be chosen taking into account the maximum dissipation (Plim) through it during full load operation.

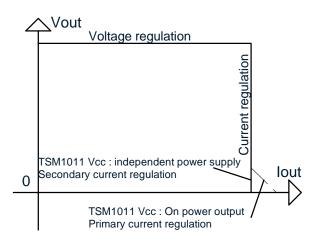
Plim = Vsense x Ilim. eq3

Therefore, for most adapter and battery charger applications, a quarter-watt, or half-watt resistor to make the current sensing function is sufficient.

The current sinking outputs of the two trans-connuctance operational amplifiers are common (to the output of the IC). This makes an ORing function which ensures that whenever the current or the voltage reaches too high values, the optocoupler is activated.

The relation between the controlled current and the controlled output voltage can be described with a square characteristic as shown in the following V/I output-power graph.

#### Figure 3 : Output voltage versus output current



# 2. Compensation

The voltage-control trans-conductance operational amplifier can be fully compensated. Both of its output and negative input are directly accessible for external compensation components.

An example of a suitable compensation network is shown in Fig.2. It consists of a capacitor Cvc1=2.2nF and a resistor  $Rcv1=22K\Omega$  in series.

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An example of a suitable compensation network is shown in Fig.2. It consists of a capacitor Cic1=2.2nF and a resistor Ric1= $22K\Omega$  in series.

#### 3. Start Up and Short Circuit Conditions

Under start-up or short-circuit conditions the TSM1011 is not provided with a high enough supply voltage. This is due to the fact that the chip has its power supply line in common with the power supply line of the system.

Therefore, the current limitation can only be ensured by the primary PWM module, which should be chosen accordingly.

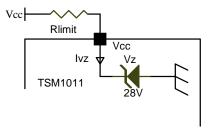
If the primary current limitation is considered not to be precise enough for the application, then a sufficient supply for the TSM1011 has to be ensured under any condition. It would then be necessary to add some circuitry to supply the chip with a separate power line. This can be achieved in numerous ways, including an additional winding on the transformer.

# 4. Voltage clamp

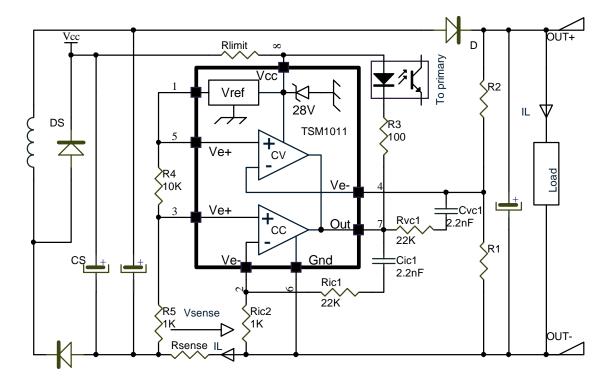
The following schematic shows how to realise a low-cost power supply for the TSM1011 (with no additional windings).Please pay attention to the fact that in the particular case presented here, this low-cost power supply can reach voltages as high as twice the voltage of the regulated line. Since the Absolute Maximum Rating of the TSM1011 supply voltage is 28V. In the aim to protect he TSM1011 against such how voltage values a internal zener clamp is integrated.

Rlimit = (Vcc-Vz)Ivz

#### Figure 4 : Clamp voltage



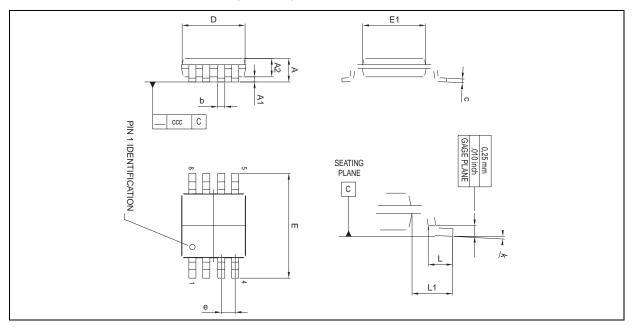




# PACKAGE MECHANICAL DATA

**57** 

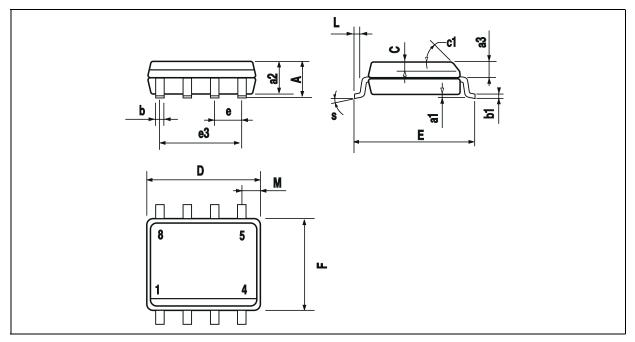
8 PINS - PLASTIC MICROPACKAGE (MiniSO8)



Dimensions -	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
A			1.100			0.043	
A1	0.050	0.100	0.150	0.002	0.004	0.006	
A2	0.780	0.860	0.940	0.031	0.034	0.037	
b	0.250	0.330	0.400	0.010	0.013	0.016	
С	0.130	0.180	0.230	0.005	0.007	0.009	
D	2.900	3.000	3.100	0.114	0.118	0.122	
E	4.750	4.900	5.050	0.187	0.193	0.199	
E1	2.900	3.000	3.100	0.114	0.118	0.122	
е		0.650			0.026		
L	0.400	0.550	0.700	0.016	0.022	0.028	
L1		0.950			0.037		
k	0d	3d	6d	0d	3d	6d	
aaa			0.100			0.004	

### PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO8)



Dimensions -	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45°	(typ.)	•	•	
D	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max.)						

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